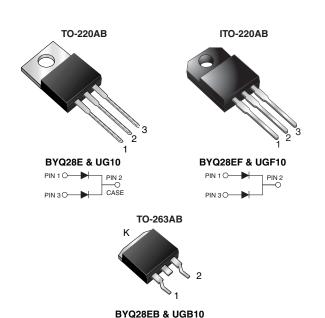


BYQ28E(F,B)-100 thru BYQ28E(F,B)-200, UG(F,B)10BCT

Vishay General Semiconductor

Dual Common Cathode Ultrafast Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)} 5 A x 2					
V _{RRM}	100 V, 150 V, 200 V				
I _{FSM}	55 A				
t _{rr}	25 ns				
V_{F}	0.895 V				
T _J max.	150 °C				

HEATSINK

FEATURES

· Glass passivated chip junction



- Ultrafast recovery times
- Soft recovery characteristics
- Low switching losses, high efficiency
- · High forward surge capability

RoHS

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, dc-to-dc converters and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG10BCT	UG10CCT	UG10DCT	LIMIT	
FANAMETEN		BYQ28E-100	BYQ28E-150	BYQ28E-200	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	٧	
Working peak reverse voltage	V_{RWM}	100	150	200	٧	
Maximum DC blocking voltage	V_{DC}	100	150	200	٧	
Maximum average forward rectified current at $T_C = 100 ^{\circ}\text{C}$ total device per diode	I _{F(AV)}	10 5			Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	55			Α	
Non-repetitive peak reverse current per diode at $t_p = 100 \mu s$		0.2			Α	
Electrostatic discharge capacitor voltage, human body model: C = 250 pF, R = 1.5 k Ω	V _C	8			kV	
Operating junction and storage temperature range	T _J , T _{STG}	T _{STG} - 40 to + 150			°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		1500			٧	

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 10 A I _F = 5 A I _F = 5 A	T _J = 25 °C T _J = 25 °C T _J = 150 °C	V _F	1.25 1.10 0.895	٧		
Maximum reverse current per diode at working peak reverse voltage		T _J = 25 °C T _J = 100 °C	I _R	10 200	μΑ		
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t _{rr}	25	ns		
Maximum reverse recovery time per diode	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	20	ns		
Maximum stored charge per diode	$I_F = 2$ A, $dI/dt = 20$ A/ μ s, $V_R = 30$ V, $I_{rr} = 0.1$ I_{RM}		Q _{rr}	9	nC		

Note:

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG10	UGF10	UGB10	UNIT	
	STIVIBUL	BYQ28E	BYQ28EF	BYQ28EB		
Typical thermal resistance per diode, junction to ambient	$R_{ heta JA}$	50	55	50	°C/W	
Typical thermal resistance per diode, junction to case	$R_{ heta JC}$	4.5	6.7	4.8		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	BYQ28E-200-E3/45	1.80	45	50/tube	Tube		
ITO-220AB	BYQ28EF-200-E3/45	1.95	45	50/tube	Tube		
TO-263AB	BYQ28EB-200-E3/45	1.77	45	50/tube	Tube		
TO-263AB	BYQ28EB-200-E3/81	1.77	81	800/reel	Tape reel		
TO-220AB	BYQ28E-200HE3/45 (1)	1.80	45	50/tube	Tube		
ITO-220AB	BYQ28EF-200HE3/45 (1)	1.95	45	50/tube	Tube		
TO-263AB	BYQ28EB-200HE3/45 (1)	1.77	45	50/tube	Tube		
TO-263AB	BYQ28EB-200HE3/81 (1)	1.77	81	800/reel	Tape reel		

Note:

(1) Automotive grade AEC Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

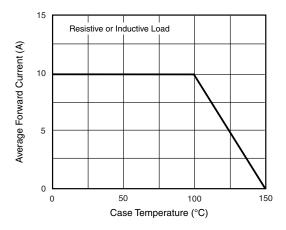


Figure 1. Forward Current Derating Curve

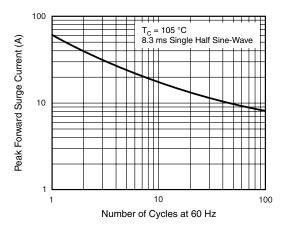


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

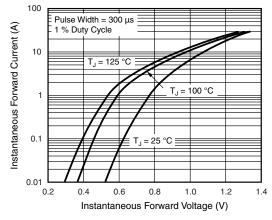


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

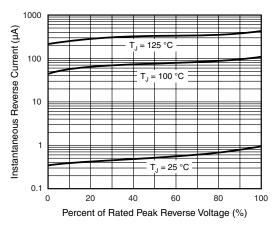


Figure 4. Typical Reverse Characteristics Per Diode

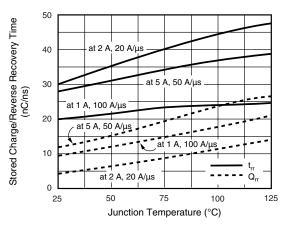


Figure 5. Reverse Switching Characteristics Per Diode

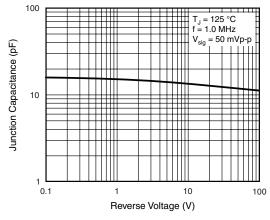


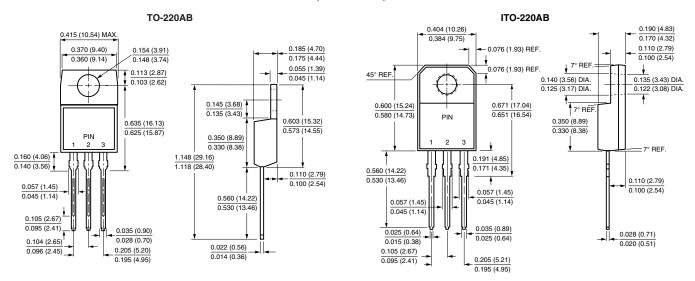
Figure 6. Typical Junction Capacitance Per Diode

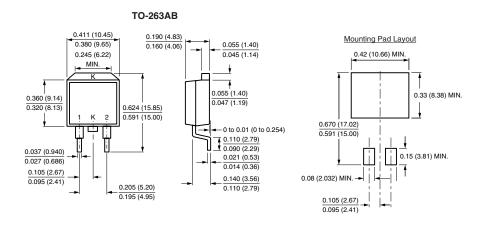
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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